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Physica B 219&amp;220 (1996) 425-427

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**PHYSICA B**

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## Dynamics of random overlayers

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### Abstract

In this paper, a method for studying the dynamics of random overlayers based on the real-space Green's function method is presented. The method provides the framework to carry out a real-space analysis of the surface modes associated with the overlayers. As an illustrative example, the method is applied to a surface alloy system of the type  $A_xB_{1-x}/B(110)$  where species A or B forms an FCC metal. Detailed formulation for the calculation of the layer DOSs from the surface to the deeper layers is also presented.

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Recently, there has been some concerted effort in the study of disordered surfaces [1-7]. In this work, we are mainly concerned with the development of a methodology to study the vibrational dynamics of a overlayer/substrate system where the overlayer is a disordered alloy. This problem requires a reliable and efficient scheme to treat both the disorder on the surface as well as the loss of the long-range order (LRO) along the direction normal to the surface. We have developed a method of real space Green's function (RSGF) which does not depend on the existence of the LRO [8, 9]. The method provides an extremely efficient and reliable scheme to calculate the local density of states (DOS) [10]. We have successfully applied the method of RSGF to study the dynamics of a relaxed and reconstructed Au(511) surface [11, 12] and the effect of disorder on the frequency spectrum of Si/Ge alloys [13]. The method is therefore ideally suited for the study of phonons of surface alloys.

To illuminate the implementation of RSGF, we consider the dynamics of surface alloy systems of the type  $A_xB_{1-x}/B(110)$  where only the surface layer is disordered, and the atomic species A or B forms a FCC

metal. For such systems, reliable force constant matrices can be obtained from the embedded atom method (EAM) [14]. Specifically, we have based our approach on the simple analytic nearest-neighbor EAM model of Johnson [15]. In the present study, we chose to ignore the possible relaxation and reconstruction of the disordered surface and its immediate neighboring layers consistent with the total internal energy derived from the EAM model. Instead, we concentrated our attention to the development of the methodology, which, in the case when the relaxation/reconstruction is taken into consideration, will still be applicable. The Green's function corresponding to the vibrational equations of motion of the overlayer/substrate system is given by

$$G = (z - H)^{-1}, \quad (1)$$

where  $z = \omega^2 + i\epsilon$ , and  $H$  is the system matrix constructed from the force constant matrices between atoms obtained as second partial derivatives of the total internal energy evaluated at the equilibrium positions. In addition, the fact that there are two different atomic masses on the surface layer has also been taken into consideration in the construction of  $H$ .

The starting point for RSGF is to express the system matrix in a block-tridiagonal form [8]. This is always

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with  $m_c$  being the number of configurations in the ensemble. Using the recipe given by Eqs. (11) and (12), a reliable average shell Green's function can be obtained by averaging over only a few configurations [13].

An examination of Eqs. (8)–(10) reveals that the average layer DOS gives the average chain (along the  $x$ -direction) DOS and also the local site DOS of a typical atom on that layer. Furthermore,  $(\rho_{ik})_j$  with  $j = 1, 2$ , or 3 gives the local site DOS along  $x$ -,  $y$ -, or  $z$ -direction. Thus we have developed a reliable and efficient method which provides the mechanism to carry out a detailed analysis of surface phonons for a disordered surface on a substrate, their vibrational characteristics, and their behavior as they go into the bulk. For example, one may first compute the surface layer DOS as a function of the 'impurity' concentration,  $x_{\text{imp}}$ , identify key vibrational modes, and observe how those modes evolve as  $x_{\text{imp}}$  varies. Furthermore, one can follow the behavior of those modes on the layer DOS's corresponding to the deeper layers, trace how the bulk behavior sets in, thus obtain an understanding of the interplay between surface and bulk properties. The method is currently being applied to study the surface dynamics of two very different over-layer/substrate systems, namely  $\text{Au}_x\text{Ag}_{1-x}/\text{Ag}(110)$  [7] and  $\text{Au}_x\text{Ni}_{1-x}/\text{Ni}(110)$  [18], and the result will be published in a forthcoming paper.

This work is partially supported by the National Science Foundation through Grant No. EHR-9108764 and Grant No. OSR-9452895.

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